2KBP08M-E

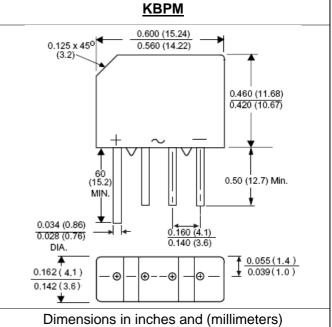
SINGLE PHASE GLASS PASSIVATED BRIDGE RECTIFIER

Voltage: 800V

Current:2.0A



Features Glass passivated chip junction 0.125 x 45⁰ (3.2) High case dielectric strength High surge current capability Ideal for printed circuit board Halogen Free (15.2 MIN 0.034 (0.86) × Method 208C DIA. **▲** 0.162(4.1) 0.142(3.6)



Mechanical Data

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Terminal: Plated leads solderable per MIL-STD 202E, Case: UL-94 Class V-0 recognized Halogen Free Epoxy Polarity: As marked on body

		derate current by 20%)	
	Symb	ol 2KBP08M-E	unit
Maximum repetitive peak reverse voltage	Vrrm	800	V
Maximum RMS voltage	Vrms	5 560	V
Maximum DC blocking voltage	Vdc	800	V
Maximum average forward rectified output curre	nt a =55℃ If(av)	2.0	A
Peak forward surge current single s superimposed on rated load (JEDEC Method)	ine-wave Ifsm	60	A
Maximum instantaneous forward voltage drop p 3.14A	ber leg at Vf	1.1	V
Rating for fusing (t < 8.3ms)	l ² t	15	A ² Se
	a = 25℃ i = 125℃ Ir	5.0 500	μΑ
Maximum thermal resistance per leg	(Note1) Rth(ja Rth(ja		°CA
Typical junction capacitance per leg at 4.0V,1MH	Iz Cj	25	pF
Operating junction and storage temperature ran	ne Tj, Tst	-55 to +150	°C

1. Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.47 x 047" (12 x 12mm) copper pads

RATINGS AND CHARACTERISTIC CURVES 2KBP08M-E

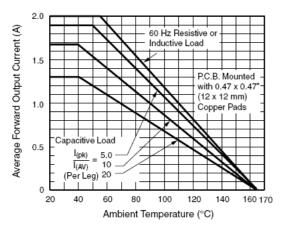


Figure 1. Derating Curve Output Rectified Current

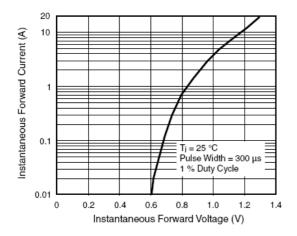


Figure 3. Typical Forward Characteristics Per Diode

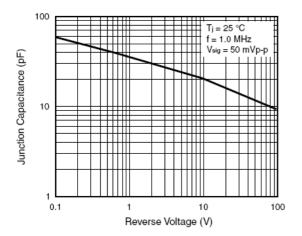


Figure 5. Typical Junction Capacitance Per Diode

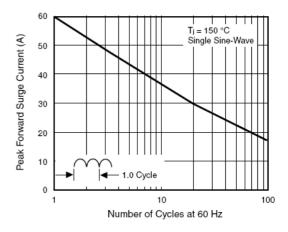


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

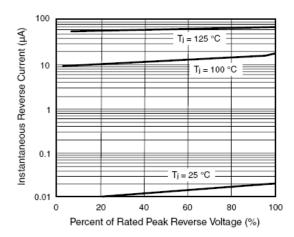


Figure 4. Typical Reverse Leakage Characteristics Per Diode

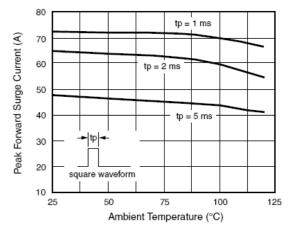


Figure 6. Non-Repetitive Peak Forward Surge Current Square Waveform